BAS16M3T5G

Switching Diode

Features

• These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Continuous Reverse Voltage	V _R	100	Vdc
Peak Forward Current	١ _F	200	mAdc
Peak Forward Surge Current	I _{FM(surge)}	500	mAdc

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation, FR-4 Board (Note 1) T _A = 25°C	P _D	260	mW
Derated above 25°C		2.0	mW/°C
Thermal Resistance, Junction-to-Ambient (Note 1)	$R_{ hetaJA}$	490	°C/W
Total Device Dissipation, FR-4 Board (Note 2) T _A = 25°C	PD	580	mW
Derated above 25°C		4.6	mW/°C
Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{ hetaJA}$	215	°C/W
Junction and Storage Temperature Range	T _J , T _{stg}	–55 to +150	°C

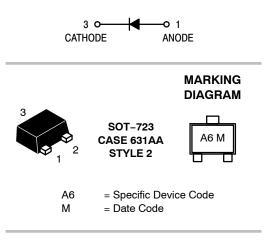
1. FR-4 @ Minimum Pad

2. FR-4 @ 1.0×1.0 Inch Pad



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ORDERING INFORMATION

Device	Package	Shipping [†]
BAS16M3T5	 SOT-723 Pb-Free)	8000 / Tape & Reel

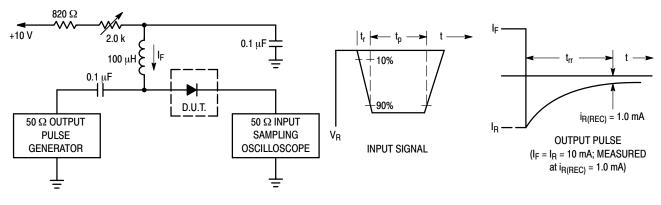
+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

BAS16M3T5G

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

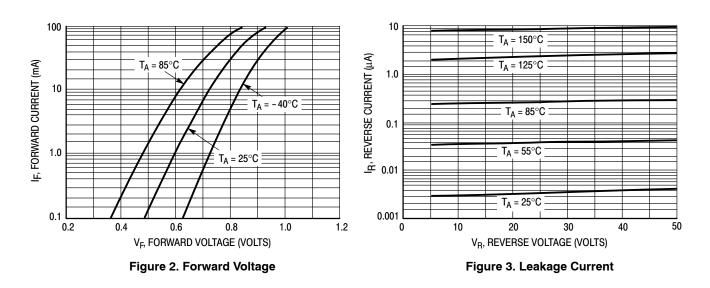
Characteristic	Symbol	Min	Max	Unit		
OFF CHARACTERISTICS						
Reverse Voltage Leakage Current ($V_R = 100 \text{ Vdc}$) ($V_R = 75 \text{ Vdc}, T_J = 150^{\circ}\text{C}$) ($V_R = 25 \text{ Vdc}, T_J = 150^{\circ}\text{C}$)	I _R	- - -	1.0 50 30	μAdc		
Reverse Breakdown Voltage (I _{BR} = 100 μAdc)	V _(BR)	100	-	Vdc		
Forward Voltage $(I_F = 1.0 \text{ mAdc})$ $(I_F = 10 \text{ mAdc})$ $(I_F = 50 \text{ mAdc})$ $(I_F = 150 \text{ mAdc})$	V _F	- - -	715 855 1000 1250	mV		
Diode Capacitance $(V_R = 0, f = 1.0 \text{ MHz})$	C _D	-	2.0	pF		
Forward Recovery Voltage (I _F = 10 mAdc, t _r = 20 ns)	V _{FR}	-	1.75	Vdc		
Reverse Recovery Time ($I_F = I_R = 10 \text{ mAdc}, R_L = 50 \Omega$)	t _{rr}	-	6.0	ns		
Stored Charge (I _F = 10 mAdc to V _R = 5.0 Vdc, $R_L = 500 \Omega$)	Q _S	-	45	рС		

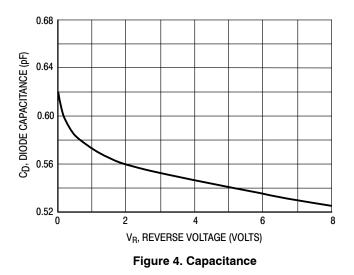
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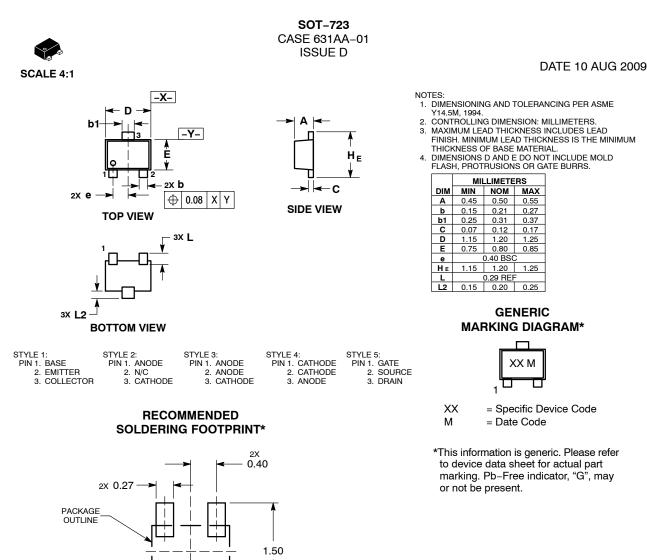
Notes: 1. A 2.0 k Ω variable resistor adjusted for a Forward Current (I_F) of 10 mA. 2. Input pulse is adjusted so I_{R(peak)} is equal to 10 mA. 3. t_p » t_{rr}











3X 0.52 - - 0.36 DIMENSIONS: MILLIMETERS

*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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 DESCRIPTION:
 SOT-723
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